



Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max (A) T _A = +25°C	
-40V	$25m\Omega @ V_{GS} = -10V$	-7.2A	
	45mΩ @ V _{GS} = -4.5V	-5.3A	

Description and Applications

This MOSFET is designed to meet the stringent requirements of automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- Motor controls
- Backlighting
- DC-DC converters
- Printer equipment

Features and Benefits

- 100% Unclamped Inductive Switch (UIS) Test in Production
- Low R_{DS(ON)} Minimizes Conduction Losses
- Fast Switching Speed Minimizes Switching Losses
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The DIODES DMP4026LSSQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/quality/product-definitions/

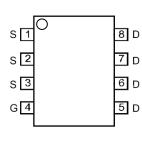
Mechanical Data

- Package: SO-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 ⁽³⁾
- Weight: 0.074 grams (Approximate)

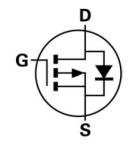


SO-8

Top View



Pin-Out Top View



Internal Schematic

Ordering Information (Note 4)

Part Number	Paakaga	Packing			
Part Number	Package	Qty.	Carrier		
DMP4026LSSQ-13	SO-8	2,500	Reel		

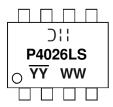
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and

Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information





Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			VDSS	-40	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 6) V_{GS} = -10V	Steady State	TA = +25°C TA = +70°C	ID	-7.2 -5.7	А
Maximum Body Diode Forward Current (Note 6)			ls	-7.2	А
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			ldм	-46	A
Pulsed Body Diode Forward Current (10µs Pulse, Duty Cycle = 1%)			Ism	-46	A
Avalanche Current, L = 0.3mH			las	-20	А
Avalanche Energy, L = 0.3mH			Eas	62	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

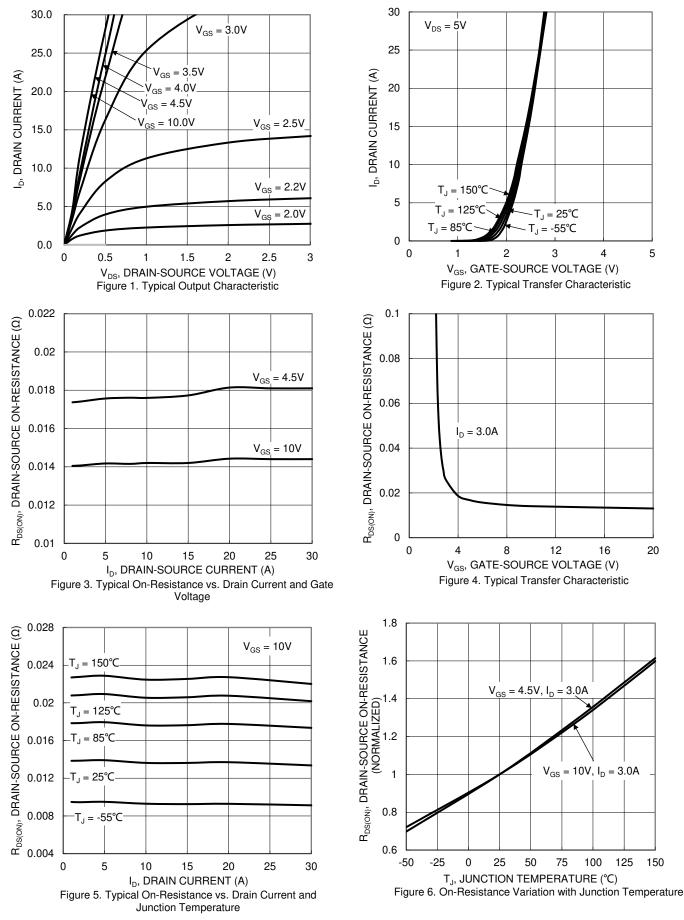
Characteristic		Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	1.5	W	
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	Reja	82.7	°C/W	
Total Power Dissipation (Note 6)		PD	2.0	W	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	Reja	60.3	°C/W	
Thermal Resistance, Junction to Case	Rejc	8.3	-C/vv		
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@TA = 25°C unless otherwise specified)

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)						L	
Drain-Source Breakdown Voltage	BV _{DSS}	-40	_	_	V	V _{GS} = 0V, I _D = -250µA	
Zero Gate Voltage Drain Current	IDSS	_	_	-1.0	μA	$V_{DS} = -40V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	VGS(TH)	-0.8	—	-1.8	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Besistance	D	_	13.9	25	mΩ	$V_{GS} = -10V, I_D = -3A$	
Static Drain-Source On-Resistance	R _{DS(ON)}	_	17.2	45	mΩ	$V_{GS} = -4.5V, I_D = -3A$	
Diode Forward Voltage	Vsd	_	-0.7	-1.0	V	V _{GS} = 0V, I _S = -1A	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	_	2083	_	pF	$V_{DS} = -20V, V_{GS} = 0V$ f = 1.0MHz	
Output Capacitance	Coss	_	221	_			
Reverse Transfer Capacitance	Crss	_	191	_			
Gate Resistance	Rg	_	2.5	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = -10V)	Q _G	_	45	_		V _{DS} = -20V, I _D = -3A	
Total Gate Charge (V _{GS} = -4.5V)	QG	_	23.5	—	nC		
Gate-Source Charge	Qgs	_	5	—	nc		
Gate-Drain Charge	Qgd	_	6.7	_			
Turn-On Delay Time	tD(ON)	_	4.3	_		$V_{GS} = -10V, V_{DD} = -20V, R_G = 6\Omega,$	
Turn-On Rise Time	tR	_	4.8	_			
Turn-Off Delay Time	tD(OFF)		71	_	ns	I _D = -3A	
Turn-Off Fall Time	tF		24	_			
Body Diode Reverse Recovery Time	trr		17.3	_	ns	Is = -3A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge	QRR		8.7	—	nC	Is = -3A, di/dt = 100A/µs	

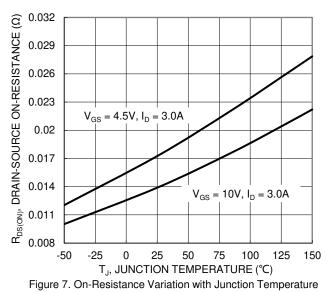
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing. Notes:

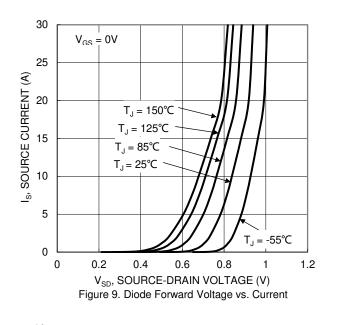


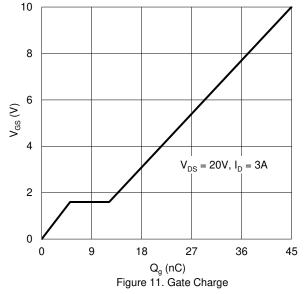


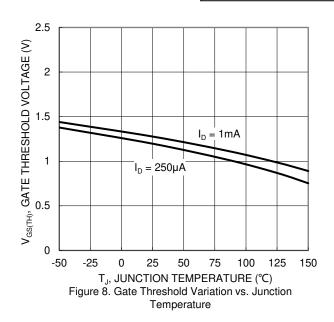


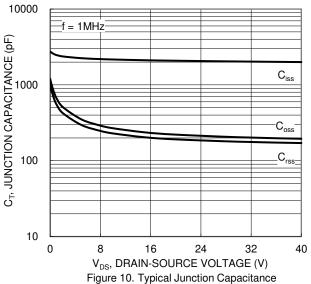


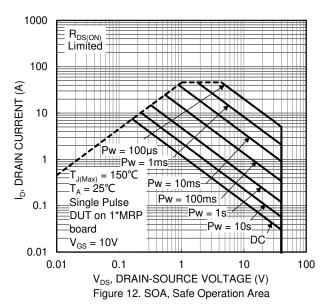




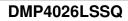




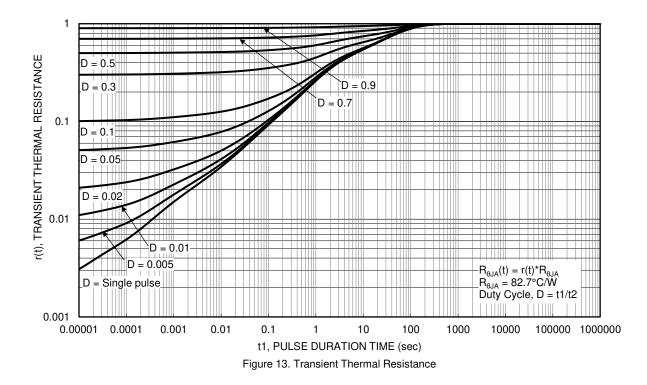




DMP4026LSSQ Document number: DS44797 Rev: 2 - 2



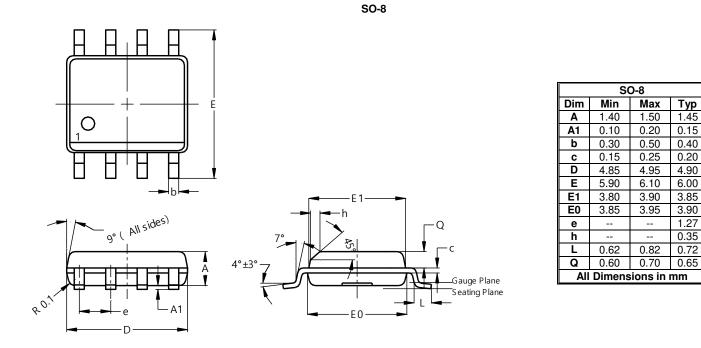






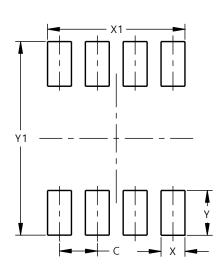
Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50

SO-8



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